

Application Notes: SY6345

40V, 300mA LDO Regulator

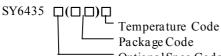
General Description

SY6345 is an efficient, precise LDO designed for high input voltage and ultra low quiescent current applications.

SY6345 provides adjustable output voltage with +/-2% accuracy and very low drop out (300mV at 300mA). Other features include the operation stability with low ESR ceramic or tantalum capacitors due to the optimized internal compensation, over current protection and thermal shutdown.

SY6345 is available in SOT23-5 package.

Ordering Information



Optional Spec Code

Ordering Number	Package type	Note
SY6345AAC	SOT23-5	

Features

- Wide input voltage range: 4V to 40V
- Low Dropout Voltage (300mV @ 300mA)
- Ultra-low quiescent current
- Extremely low shutdown current
- Stability with tantalum or ceramic capacitors
- Excellent load and line regulation
- +/-2% 0.6V reference accuracy
- 300mA maximum load current
- Enable control input
- Over current protection
- Thermal shutdown
- Compact SOT23-5 package

Applications

- Battery powered Applications
- Automotive Applications
- Gateway Applications
- Remote Keyless Entry Systems
- SMPS post-regulator/ DC-DC modules

Typical Applications

IN

EN

GND

Figure 1. Schematic Diagram

Enable Signal

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OUT

ADJ

VIN

CIN

2.2uF

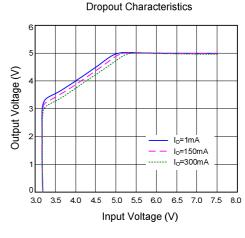


Figure 2. Dropout Characteristics

1

Vout

COUT

2.2uF

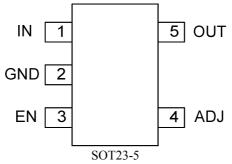
R

R



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Pinout (top view)

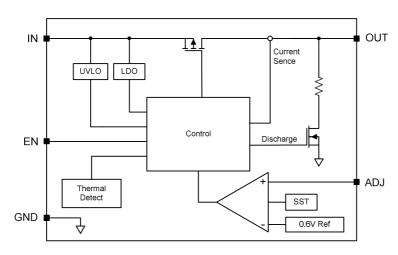


Top mark: YSxyz for (Device code: YS, x=year code, y=week code, z= lot number code)

Function Pin Description

Pin Name	Pin Number	Pin Description				
IN	1	IC power supply input. Bypass this pin to Ground pin with a capacitor.				
GND	2	Ground pin.				
EN	3	Enable pin. Pull it low to shutdown or pull it high to enable, do not leave				
		floating.				
ADJ	4	Output voltage adjust pin. Feedback the output voltage through resistor				
		voltage divider network. Vo=0.6×(1+R1/R2)				
OUT	5	Output pin. Bypass this pin to Ground pin with a low ESR ceramic				
		capacitor.				

Function Block





Absolute Maximum Ratings (Note 1)

IN to GND	0.3V to 40V
OUT, EN, ADJ to GND	0.3V to 0.3V+Vin
Power Dissipation, PD (a) T _A = 25°C SOT23-5	0.6W
Package Thermal Resistance	
θ _{IA}	170°C/W
θ _{IC}	130°C/W
Storage Temperature	65C to +150°C
Junction Temperature (T _J)	+150°C
Lead Temperature (Soldering, 10sec.)	+260°C

Recommended Operating Conditions

Supply Input Voltage	4V to 40V
Junction Temperature (T _J)	
Ambient Temperature Range	40°C to 85°C



Electrical Characteristics

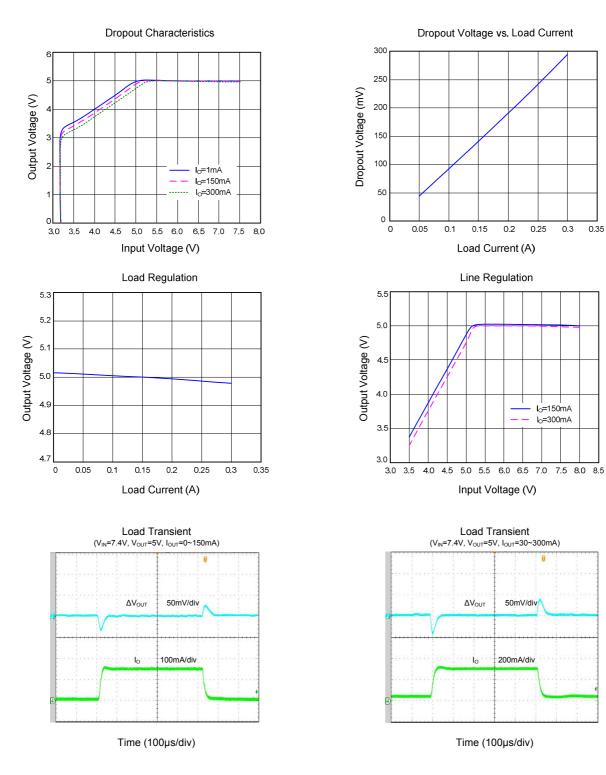
$(V_{IN} = 12V, V_{EN} = V_{IN}, TA = 25^{\circ}C ur$	less otherwi	se specified)				
Parameter	Symbol	Test Conditions	Min	Typical	Max	Unit
Input Voltage	V _{IN}	I _{OUT} =10mA	4		40	V
Reference Voltage	V _{REF}	V _{IN} =12V, Io=10mA	588	600	612	mV
Line Regulation	ΔV_{LNR}	$V_{IN} = (V_{OUT} + 0.3V)$ to 40V, $I_0 = 10mA$		1		mV/V
Load Regulation	ΔV_{LDR}	I _O =10mA to 300mA		0.25	1	%
		I _O =10mA		10		mV
Dropout Voltage	V_{IN} - V_{OUT}	I _O =150mA		150		mV
		I ₀ =300mA		300		mV
Quiescent Current	I _Q	No Load		7	10	μΑ
Shutdown Current	I _{SHDN}	$V_{EN}=0V_V_{IN}=24V$			1.25	μΑ
Output Current	Io	$V_{IN} = V_{OUT} + 0.6V$	0		300	mA
Output Current limit	I _{LIM}	$V_{IN} = 6V, V_{OUT} = 0.9xV_{OUT}$ (normal)	350		750	mA
	PSRR	f=1kHz, C _{OUT} =10uF		60		dB
Power-supply Rejection Ratio		f=150kHz, C _{OUT} =10uF		30		dB
Input UVLO Threshold	V _{UVLO}	V _{IN} rising			3.8	V
UVLO Hysteresis	V _{UVLO_th}			0.2		V
Shutdown Discharge Resistance	R _{DIS}			600		Ω
Enable Input Logic-High Voltage	V _{EN_H}	V_{IN} =5V to 40V	1.5			V
Enable Input Logic-Low Voltage	V _{EN_L}	V_{IN} =5V to 40V			0.4	V
Thermal Shutdown Temperature	T _{SD}			150		°C
Thermal Shutdown hysteresis	T _{HYS}			20		°C

Note 1: Stresses beyond the "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note 2: θ_{JA} is measured in the natural convection at TA = 25°C on a low effective two-layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard.

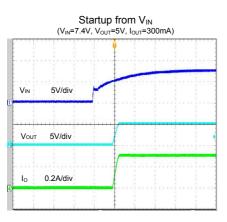
Note 3: The device is not guaranteed to function outside its operating conditions

Typical Performance Characteristics

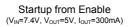


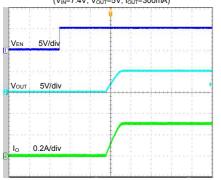


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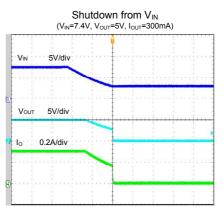


Time (2ms/div)

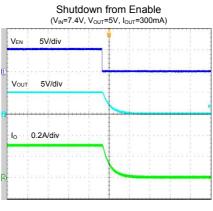




Time (800µs/div)



Time (2ms/div)



Time (100µs/div)

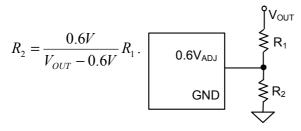


Application information

The SY6345 is a 300mA linear regulator with a low drop out voltage. Like any low-dropout regulator, SY6345 requires input and output decoupling capacitors.

Feedback resistor dividers R1 and R2:

Choose R_1 and R_2 to program the proper output voltage. To minimize the power consumption under light loads, it is desirable to choose large resistance values for both R_1 and R_2 . A value of between $10k\Omega$ and $1M\Omega$ is highly recommended for both resistors. If V_{OUT} is 3.3V, R_1 =100k is chosen, then using following equation, R_2 can be calculated to be 22.1k:



Input capacitor CIN:

An input capacitor about 2.2uF is required between the device input pin and ground pin. A typical X5R or better grade ceramic capacitor is recommended in this application. This input capacitor must be located close to the device to minimize the input noise.

Output capacitor Cour:

For transient stability, SY6345 is designed specifically to work with very small ceramic output capacitors. 2.2uF output capacitance can be used in this application. Higher capacitance values help to improve transient. The output capacitor's ESR is critical because it forms a zero to provide phase lead which is required for loop stability.

Dropout Voltage:

SY6345 has a very low dropout voltage due to its extra low $R_{DS(ON)}$ of the main PMOS determines the lowest usable supply .

 $V_{DROPOUT} = V_{IN} - V_{OUT} = R_{DS(ON)} \times I_{OUT}$

Over Current and Short Circuit Protection:

The device includes over current and short circuit protection. The current limitation circuit regulates the output current to its limitation threshold to protect IC from damage. Under over current or short circuit condition, the power loss of the IC is relative high. And that may trigger the thermal protection.

Thermal Considerations:

The SY6345 can deliver a current of up to 300mA over the full operating junction temperature range. However, the maximum output current must be derated at higher ambient temperature to ensure the junction temperature does not exceed 125 °C. With all possible conditions, the junction temperature must be within the range specified under operating conditions. Power dissipation can be calculated based on the output current and the voltage drop across regulator.

 $P_{D} = (V_{IN} - V_{OUT}) \times I_{OUT} + V_{IN} \times I_{GND}$

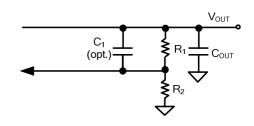
The final operating junction temperature for any set of condition can be estimated by the following thermal equation:

 $P_{D(MAX)} = (T_{J(MAX)} - T_A)/\theta_{JA}$

Where $T_{J(MAX)}$ is the maximum junction temperature of die (125°C) and T_A is the maximum ambient temperature. The junction to ambient thermal resistance (θ_{JA}) footprint is 170°C/W for SOT23-5 package.

Load Transient Considerations:

The SY6345 regulator IC integrates the compensation components to achieve good stability and fast transient responses. In some applications, adding a small ceramic cap in parallel with R1 may further speed up the load transient responses and is thus recommended for applications with large load transient step requirements.



Layout Design:

Good board layout practices must be used or instability can be induced because of ground loops and voltage drops, and large PCB copper area can

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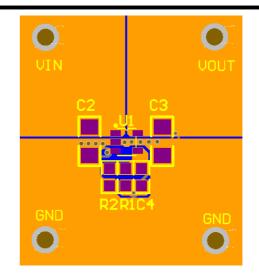


improve the thermal performance. The input and output capacitors MUST be directly connected to the input, output, and ground pins of the device using traces which have no other currents flowing through them.

The best way to do this is to layout $C_{\rm IN}$ and $C_{\rm OUT}$ near the device with short traces to the $V_{\rm IN}, \, V_{\rm OUT},$ and ground pins. The regulator ground pin should be connected to the external circuit ground so that the regulator and its capacitors have a "single point ground".

Below is the recommended PCB layout diagram:

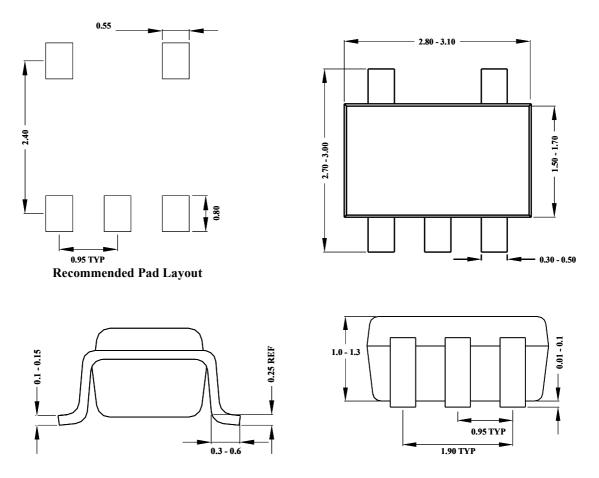
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AN_SY6345



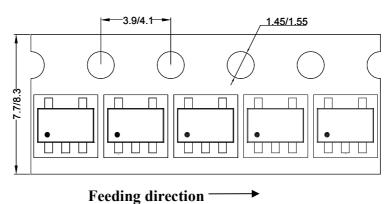


Notes: All dimensions are in millimeters. All dimensions don't include mold flash & metal burr.

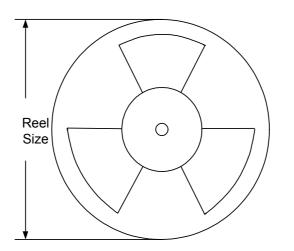


1. Taping orientation





2. Carrier Tape & Reel specification for packages



Package	Tape width	Pocket	Reel size	Trailer	Leader length	Qty per
types	(mm)	pitch(mm)	(Inch)	length(mm)	(mm)	reel
SOT23-5	8	4	7"	280	160	3000

3. Others: NA

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